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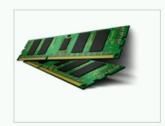
Support

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16Gb Mass Storage: MT29F16G08ABCCBH1-12



Specifications

Technology: Mass Storage

Module Density:

Part Status Code: End of Life

RoHS: Yes

Number of Components:

Depth: 2Gb Bus Width: x8 Pin Count: 100-ball

Operating Temp: 0C to +70C

MT/s: 166 MT/s Industry Speed: CAS Latency: Voltage: 3.3V Component Config:

ECC:

Module Rank:

Register:

Data Sheets

Datasheet: NAND Flash, SLC, 16/32/64Gb,

Async/Sync, M72A . Rev. Date: 07/2011, File Size:

3.08 MB

Certifications

RoHS Certificate of Compliance.pdf

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Tech Notes

Documentation

Sim Models

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Please Note: Distributor inventory is an estimate and may not reflect actual available memory. Some links on this page will take you from the Micron web site. Micron does not control the content on these web sites.

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For more than 30 years, Micron's teams of dreamers, visionaries, and scientists have redefined innovation—designing and building some of the world's most advanced memory and semiconductor technologies. We develop the technologies that transform what's possible. In fact, you likely use our memory every day—in products from computing, networking, and server applications, to mobile, embedded, consumer, automotive, and industrial designs. As one of the most prolific patent holders in the world we continually rethink, recast, and advance new ideas to bring innovation to broader markets and find ways our technology can inspire new applications or make fundamental improvements to existing designs. Our roots are in memory, the core strength of our business. As we look toward the future, we'll continue to build on our past achievements by leveraging the synergies between our core memory business and diversified products and technologies that help drive innovation and growth in new markets.